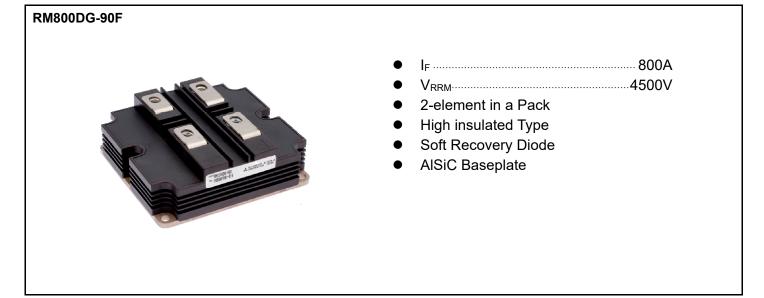


< HIGH VOLTAGE DIODE MODULES >

# **RM800DG-90F**

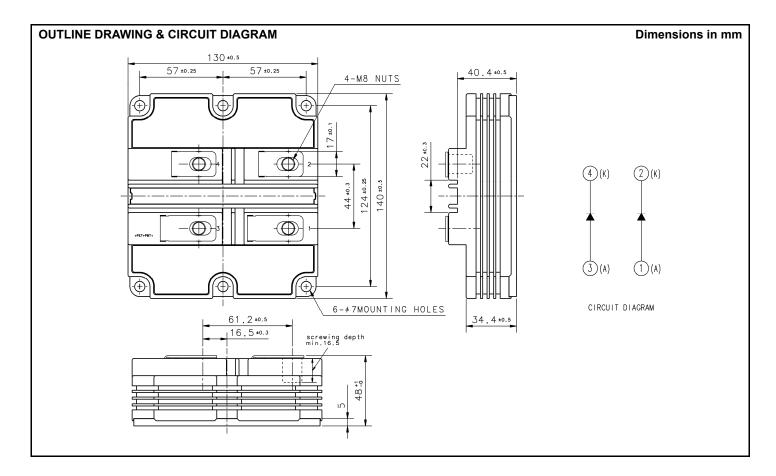
HIGH POWER SWITCHING USE INSULATED TYPE

High Voltage Diode Modules



### APPLICATION

Traction drives, High Reliability Converters / Inverters, DC choppers



#### MAXIMUM RATINGS

Symbol	Item	Conditions	Ratings	Unit
V <sub>RRM</sub>	Depatitive peak reverse valtage	T <sub>j</sub> = −40+125°C	4500	v
	Repetitive peak reverse voltage	$T_i = -50^{\circ}C$	4400	v
I <sub>F</sub>	Forward current	DC, $T_c = 65^{\circ}C$	800	А
I <sub>FSM</sub>	Surge forward current	$T = 125^{\circ}C$ t = 10 ms    o f sins ways $V = 0.V$	6.5	kA
l <sup>2</sup> t	Surge current load integral	$T_{j\_start}$ = 125°C, $t_p$ = 10 ms, Half-sine wave, $V_R$ = 0 V	211	kA <sup>2</sup> s
P <sub>tot</sub>	Maximum power dissipation	T <sub>c</sub> = 25°C	4160	W
V <sub>iso</sub>	Isolation voltage	RMS, sinusoidal, f = 60 Hz, t = 1 min.	10200	V
Ve	Partial discharge extinction voltage	RMS, sinusoidal, f = 60 Hz, $Q_{PD} \le 10 \text{ pC}$	3500	V
Tj	Junction temperature		-50 ~ +150	°C
T <sub>jop</sub>	Operating junction temperature		-50 ~ +125	°C
T <sub>stg</sub>	Storage temperature		-55 ~ +75	°C

#### **ELECTRICAL CHARACTERISTICS**

Sympol	Itom	Conditions		Limits			Unit
Symbol	Item			Min	Тур	Max	Unit
1.	Demetitive revenue evenuent	$V_{RM} = V_{RRM}$	T <sub>j</sub> = 25°C	_		1.0	mA
RRM	Repetitive reverse current		T <sub>j</sub> = 125°C	_	3.0	_	ША
V		L = 000 A	T <sub>j</sub> = 25°C		2.55		v
V <sub>FM</sub>	Forward voltage	I <sub>F</sub> = 800 A	T <sub>i</sub> = 125°C		2.85	3.45	v
	Reverse recovery time		T <sub>j</sub> = 25°C	_	0.70	_	
t <sub>rr</sub>		V <sub>CC</sub> = 2800 V I <sub>F</sub> = 800 A	T <sub>i</sub> = 125°C	_	0.90	_	μs
	Reverse recovery current		T <sub>i</sub> = 25°C		700		А
Irr			T <sub>j</sub> = 125°C	_	760	_	A
		−d <sub>i</sub> /d <sub>t</sub> = 2600 A/μs @ T <sub>j</sub> = 25°C −d <sub>i</sub> /d <sub>t</sub> = 2400 A/μs @ T <sub>j</sub> = 125°C	T <sub>j</sub> = 25°C	_	660	_	
Q <sub>rr</sub>	Reverse recovery charge		T <sub>i</sub> = 125°C	_	1040	_	μC
-	Device no concernent (Note 1)		T <sub>j</sub> = 25°C	_	0.96	_	
Erec(10%)	Reverse recovery energy (Note 1)	L <sub>s</sub> = 150 nH	T <sub>j</sub> = 125°C	_	1.50		J
-		Inductive load	T <sub>i</sub> = 25°C		1.10		
E <sub>rec</sub>	Reverse recovery energy		T <sub>j</sub> = 125°C	_	1.70	_	J

#### THERMAL CHARACTERISTICS

Sympol	ltom	Conditions	Limits			Linit
Symbol	Item	Conditions	Min	Тур	Max	Unit
R <sub>th(j-c)</sub>	Thermal resistance	Junction to Case (per 1/2 module)			30.0	K/kW
R <sub>th(c-s)</sub>	Contact thermal resistance	Case to heat sink, $\lambda_{grease} = 1 \text{ W/m}^{\star}\text{k}$ D <sub>(c-s)</sub> = 100 µm (per 1/2 module)		24.0		K/kW

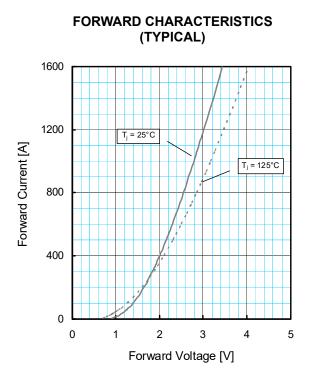
#### **MECHANICAL CHARACTERISTICS**

Symbol	Item	Conditions	Limits			Unit
			Min	Тур	Max	Unit
Mt	<ul> <li>Mounting torque</li> </ul>	M8 : Main terminals screw	7.0		22.0	N∙m
Ms		M6 : Mounting screw	3.0		6.0	N∙m
m	Mass		_	1.0		kg
CTI	Comparative tracking index		600			—
d <sub>a</sub>	Clearance		26.0			mm
ds	Creepage distance		56.0			mm
$L_{PAK}$	Parasitic stray inductance		—	22.0		nH
R <sub>AA'+KK'</sub>	Internal lead resistance	$T_c = 25^{\circ}C$	_	0.14	_	mΩ

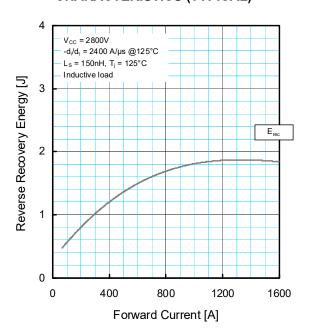
Note 1. Note 2.

 $\mathsf{E}_{\mathsf{rec}(10\%)}$  are the integral of 0.1*V<sub>R</sub>* x 0.1*I<sub>F</sub>* x dt. Definition of all items is according to IEC 60747, unless otherwise specified.

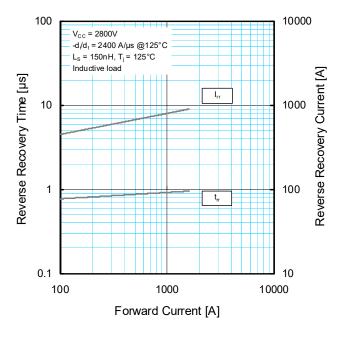
#### PERFORMANCE CURVES



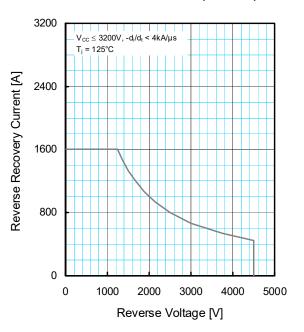
#### **REVERSE RECOVERY ENERGY** CHARACTERISTICS (TYPICAL)



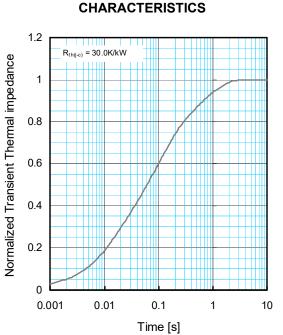
REVERSE RECOVERY CHARACTERISTICS (TYPICAL)



#### REVERSE RECOVERY SAFE OPERATING AREA (RRSOA)



#### PERFORMANCE CURVES



TRANSIENT THERMAL IMPEDANCE



 $Z_{th(j-c)}(t) = \sum_{i=1}^{n} R_{i} \left\{ 1 - exp^{\left(-\frac{t}{\tau_{i}}\right)} \right\}$ 

	1	2	3	4
R <sub>i</sub> [K/kW]	0.0055	0.2360	0.4680	0.2905
t <sub>i</sub> [sec]	0.0001	0.0131	0.0878	0.6247

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